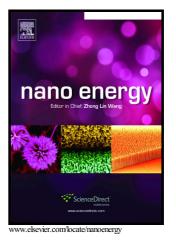
## Author's Accepted Manuscript

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 PII:
 S2211-2855(18)30399-9

 DOI:
 https://doi.org/10.1016/j.nanoen.2018.06.004

 Reference:
 NANOEN2785

To appear in: Nano Energy

Received date: 22 January 2018 Revised date: 28 May 2018 Accepted date: 1 June 2018

Cite this article as: Xian-Gang Hu, Peng-Xiang Hou, Chang Liu, Feng Zhang, Gang Liu and Hui-Ming Cheng, Small-Bundle Single-Wall Carbon Nanotubes for High-Efficiency Silicon Heterojunction Solar Cells, *Nano Energy*, https://doi.org/10.1016/j.nanoen.2018.06.004

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## Small-Bundle Single-Wall Carbon Nanotubes for High-Efficiency Silicon Heterojunction Solar Cells

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## ABSTRACT

Single-wall carbon nanotubes (SWCNTs) are a promising material for constructing high-performance photovoltaic conversion devices due to their excellent optical and electrical properties. Here we report a high-quality, small-bundle SWCNT film for the fabrication of high-efficiency silicon heterojunction solar cells. The SWCNT film synthesized by floating catalyst chemical vapor deposition has a low sheet resistance of 180  $\Omega$  sq<sup>-1</sup> at 90% transmittance, which is more than two times lower than that of previously reported pristine SWCNTs used for SWCNT/Si heterojunction solar cells. Effects of the thickness of SWCNT film and device active area on the performance of the cells were investigated, and high power conversion efficiencies of 14.2% and 11.8% were achieved for devices with active areas of 2.3

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